L Number	Hits	Search Text	DB	Time stamp
-	770	(250/330 or 250/332 or 250/338.1 or	USPAT;	2003/05/31 17:14
i		250/338.3 or 250/338.4) and (ir or	US-PGPUB;	
]		infrared) and resistor	EPO; JPO;	
}			DERWENT;	}
1			IBM_TDB	
-	128	(250/330 or 250/332 or 250/338.1 or	USPAT;	2003/06/02 19:18
]		250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	
		250/340) and (ir or infrared) and resistor	EPO; JPO;	1
1		and shield	DERWENT;	
	163	(250/330 or 250/332 or 250/338.1 or	IBM_TDB   USPAT;	2003/06/02 19:18
-	103	250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	2003/06/02 19:16
}		250/338.3 of 250/338.4 of 250/339.2 of 250/340) and (ir or infrared) and resistor	EPO; JPO;	
1		and (shield or shielding)	DERWENT;	
		and (Shield of Shielding)	IBM TDB	
} _	1	(250/330 or 250/332 or 250/338.1 or	USPAT;	2003/06/02 14:34
		250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	
		250/340) and (ir or infrared) and resistor	EPO; JPO;	!
<b>,</b>		and (shield or shielding) and overhang	DERWENT;	
			IBM_TDB	
-	6	(250/330 or 250/332 or 250/338.1 or	USPĀT;	2003/06/02 14:38
		250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	!
		250/340) and (ir or infrared) and resistor	EPO; JPO;	
}		and (shield or shielding) and hang	DERWENT; IBM TDB	
_	37	(250/330 or 250/332 or 250/338.1 or	USPAT;	2003/06/02 19:18
]	,	250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	2003/00/02 13.10
		250/340) and (ir or infrared) and resistor	EPO; JPO;	
		and (shield or shielding) and pixel	DERWENT;	
			IBM TDB	
-	78	(250/330 or 250/332 or 250/338.1 or	USPAT;	2003/06/02 17:12
		250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	
		250/340) and (ir or infrared) and resistor	EPO; JPO;	
}		and (shield or shielding) and (reflect or	DERWENT;	
_	51	reflecting or reflection) (250/330 or 250/332 or 250/338.1 or	IBM TDB	2002/06/02 10:12
į	31	250/338.3 or 250/338.4 or 250/339.2 or	USPAT; US-PGPUB;	2003/06/02 18:12
1		250/330.3 of 250/330.4 of 250/339.2 of 250/340) and (ir or infrared) and resistor	EPO; JPO;	
		and (absorbing) and (silicon adj nitride)	DERWENT;	
		j	IBM TDB	
-	30	(250/330 or 250/332 or 250/338.1 or	USPAT;	2003/06/02 18:14
!		250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	
		250/340) and (ir or infrared) and resistor	EPO; JPO;	
i		and (absorbing) and (silicon adj oxide)	DERWENT;	
	36	/250/220 250/222 250/220 1	IBM TDB	2002/06/02 10 16
-	36	(250/330 or 250/332 or 250/338.1 or 250/338.3 or 250/338.4 or 250/339.2 or	USPAT; US-PGPUB;	2003/06/02 18:16
		250/338.3 Of 250/338.4 Of 250/339.2 Of	EPO; JPO;	
]		and (absorbing adj layer)	DERWENT;	
		and targetaing and target,	IBM TDB	
-	256	(250/330 or 250/332 or 250/338.1 or	USPĀT;	2003/06/02 18:34
}		250/338.3 or 250/338.4 or 250/339.2 or	US-PGPUB;	
		250/340) and (ir or infrared) and resistor	EPO; JPO;	
		and (absorbing or absorb)	DERWENT;	
			IBM TDB	